

DECLARATION FOR PATENT APPLICATION AND POWER OF ATTORNEY



Page 1 of 2

Attorney Docket No. 03W089

- Original
- Continuation
- Division
- Continuation-in-part
- Supplemental

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

Low Power Current Input Delta-Sigma ADC Using Injection FET Reference

the specification of which

- (check one) is attached hereto.
 was filed on 01/29/2004 as Application No. 10/769,111 and (a) [other than supplemental] was amended on _____ or (b) [supplemental] with amendments through n/a.

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, §1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prior Foreign Application(s)

Number	Country	Day/Month/Year Filed
--------	---------	----------------------

Priority Claimed
 Yes No

I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code §112, I acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, §1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

Application Serial No.	Filing Date	Status
		(patented, pending, abandoned)

Raytheon Company

Intellectual Property & Licensing, Loc: EO/E04/N119

2000 East El Segundo Boulevard, P. O. Box 902

El Segundo CA 90245-0902, Attorney: W. C. Schubert (805) 562-2685 phone

re: Low Power Current Input Delta-Sigma ADC Using Injection FET Reference

I hereby appoint the following attorneys, or agent and attorneys, to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith:

William C. Schubert	Registration No. 30,102
Edward S. Roman	Registration No. 25,778
Philip P. Berestecki	Registration No. 26,052
Leonard A. Alkov	Registration No. 30,021
Colin M. Raufer	Registration No. 40,781
John E. Gunther	Registration No. 43,649

Address all correspondence to Intellectual Property & Licensing, Raytheon Company, Bldg. EO/E04 M/S N119, P.O. Box 902, El Segundo, California 90245-0902. Address all telephone calls to William C. Schubert, 805-562-2108, Raytheon Company, Goleta, California 93117.

I HEREBY DECLARE THAT ALL STATEMENTS MADE HEREIN OF MY OWN KNOWLEDGE ARE TRUE AND THAT ALL STATEMENTS MADE ON INFORMATION AND BELIEF ARE BELIEVED TO BE TRUE; AND FURTHER THAT THESE STATEMENTS WERE MADE WITH THE KNOWLEDGE THAT WILLFUL FALSE STATEMENTS AND THE LIKE SO MADE ARE PUNISHABLE BY FINE OR IMPRISONMENT, OR BOTH, UNDER SECTION 1001 OF TITLE 18 OF THE UNITED STATES CODE AND THAT SUCH WILLFUL FALSE STATEMENTS MAY JEOPARDIZE THE VALIDITY OF THE APPLICATION OR ANY PATENT ISSUED THEREON.

FULL NAME OF SOLE OR JOINT INVENTOR Christopher L. Fletcher	INVENTOR'S SIGNATURE 	DATE Aug 13, 2004
RESIDENCE (CITY AND STATE) Santa Barbara, California	CITIZENSHIP USA	
POST OFFICE ADDRESS 4121 Sycamore Canyon Road, Santa Barbara, California 93108		
FULL NAME OF SOLE OR JOINT INVENTOR Martins Skele	INVENTOR'S SIGNATURE	DATE
RESIDENCE (CITY AND STATE) Langley, Washington	CITIZENSHIP USA	
POST OFFICE ADDRESS 3079 Saratoga Road, Langley, Washington 98260		
FULL NAME OF SOLE OR JOINT INVENTOR	INVENTOR'S SIGNATURE	DATE
RESIDENCE (CITY AND STATE)	CITIZENSHIP	
POST OFFICE ADDRESS		
FULL NAME OF SOLE OR JOINT INVENTOR	INVENTOR'S SIGNATURE	DATE
RESIDENCE (CITY AND STATE)	CITIZENSHIP	
POST OFFICE ADDRESS		

*Government contract related N66001-02-C-8078

Raytheon Company
Intellectual Property & Licensing, Loc: EO/E04/N119
2000 East El Segundo Boulevard, P. O. Box 902
El Segundo CA 90245-0902, Attorney: W. C. Schubert (805) 562-2685 phone